

Subject Index

- A 15 compounds 12, 86
- AgBr 152, 172
- AgCl 152, 172
- Ag(CN)_x⁻, SERS 199, 200
- AlSb 117, 153
- , scattering efficiency 93
- As₂Se₃ glasses 83
- Absorption edge, direct 117
- -, E_0 , $E_0 + \Delta_0$ 117
- -, E_1 , $E_1 + \Delta_1$ 119
- -, indirect 117
- -, lowest 117
- Absorption spectrum, InAs 118
- Acoustic plasmons 2
- Aliasing 202
- Alkali halides 64, 85, 86
- vapors 241
- Alkaline earth chalcogenides 64
- Amorphous materials 2, 10, 19, 20, 76–85
- Antifluorites 64
- Antiresonance 35, 44, 223
- A · p versus E · r perturbation 105
- ARCS (angular-resolved coherent spectroscopy) 211, 228
- Atomic displacement, representations 51–55

- B₂O₃ glasses 82, 83
- BaF₂ 94, 98, 127, 128
- BaTiO₃, silent modes 237
- BeO, scattering efficiency 93
- Background subtraction 196
- Barn 24
- Benzene, scattering cross section 92, 93, 234, 235
- , TPA 235
- Biexcitons 240, 241
- Birefringence, intensity-induced 220
- Bloch's theorem 26, 38
- Blooming 202
- Bond charge model 65
- polarizability 32, 66
- -, second order 67
- -, transferability 32
- rigidity parameter ζ 67, 124

- Born-Oppenheimer approximation 106
- Bose-Einstein factor 31
- Bound state, two-phonon 66
- Boxcar 201
- Boxcars (CARS with box-shaped beam) 211, 228
- Bragg scattering 27
- -, magnetic 13
- Branching ratio 146
- Brillouin scattering 2, 4, 5, 69
- -, by magnons 71
- -, by piezoelectric phonons 129
- -, cross section 72–76
- -, opaque materials 11, 71
- -, resonant 165
- tensor 73

- C₂H₃Cl 34, 35
- CaCO₃ 92, 94, 223, 238
- CaF₂ 43, 50, 53, 98
- , scattering efficiency 127, 128
- Carbon, amorphous
- CARS (coherent antistokes Raman scattering) 19, 90–92, 207–211, 213, 215, 216, 218, 219, 221–231
- , centrosymmetric crystals 229, 233
- , noncentrosymmetric crystals 230
- Cascade model 145–147, 213
- CCD (charge coupled devices) 180
- CCl₄ 34, 35
- CdS 13, 70, 74, 146, 152, 160, 167, 238
- , phonon eigenvectors 53
- , resonant allowed and forbidden scattering 136
- , scattering efficiency 93
- CdSe 167
- CdTe 165
- Cells, photovoltaic
- Chalcopyrite, vibrational eigenvectors 54, 55
- Charge, dynamical 59
- Chromatic aberration 192
- CHRS (coherent Hyper-Raman-Scattering) 211
- CoCO₃ 15

- CrBr₃ 15
 CsBr 238
 CsI, HRS 238, 239
 CsI, multiphonon scattering 167, 168
 CS₂, cross section 98
 CsNiF₃ 15
 Coherent scattering techniques 207, 208
 Collection angle 40, 41
 Compounds
 -, II-IV 64
 -, III-V 64
 Computer 194-197
 -, background subtraction with 196-197
 - block diagram 196
 -, data accumulation with 196
 -, fixed pattern correction with 196
 - interface 194, 195
 - programming 195
 -, selective scanning with 187
 -, setting scan format with 194
 -, system response correction with 197
 - system selection 195
 Cooling
 -, ISIT 188
 -, ISPD 190, 191
 -, SIT tubes 186
 -, SPD 190, 191
 Creation and annihilation operators
 - - - -, electrons 102
 - - - -, phonons 111
 - - - -, photons 101
 Critical points
 - -, E_0 , $E_0 + \Delta_0$ 21
 - -, E_1 , $E_1 + \Delta_1$ 21
 - -, one-dimensional 117
 - -, three-dimensional 112-115
 - -, two-dimensional 116
 - -, van Hove 27, 28, 42, 65, 112-116
 Cross section 24
 - -, absolute 37, 92
 - -, Brillouin 72-75
 - -, differential 23
 - -, elastic scattering 22
 - -, polaritons 60
 - -, power 37
 - -, quantum 37
 - -, Raman 31, 105
 - -, Thompson 24
 CRSS (coherent Raman scattering) 208, 213, 218
 Crystal momentum (*see also* pseudomomentum, wave vector) 27, 38
 CSRS (coherent Stokes Raman spectroscopy) 211, 229
 CuBr 62, 70, 74, 237, 240, 241
 CuCl 62, 117, 169, 237, 240, 241
 -, CARS 233, 234
 -, D4WM 231
 CuI 62, 240, 241
 Cu₂O 21, 144, 152
 -, acoustic phonons 171
 -, optical phonons 169
 -, resonance at forbidden excitons 170
 -, resonant scattering 168-171
 -, three-phonon processes 171
 Data analysis 196, 197
 DEC 196
 Defect-induced Raman scattering 85
 Defect-induced scattering, resonance 87
 Deformation potential 28, 42, 111, 147, 170, 218
 - -, b 150, 165
 - -, d 150, 165
 - -, d_0 121, 123, 124, 128, 153, 154
 - -, $d_{1,0}^2$ 124, 157
 - -, $d_{3,0}^2$ 124, 157
 - -, d_1^2 , d_3^2 , d_3^3 , ϵ 151
 - -, second-order D_1 139, 140
 - -, tight binding calculation 124
 Degradation, MCP 181
 DEMC (deep etch metal cap) 186
 Density fluctuations, spatial 28
 - matrix 215, 218
 Depolarization ratio 25, 78
 - -, maximum 25
 Diamond 50, 53, 64, 123, 152, 231
 -, bond polarizability 66, 67
 -, CARS spectrum 225
 -, elastooptic constants 67
 -, Raman polarizability 68, 126, 127
 -, RIKES 232
 -, scattering efficiency 92, 93, 95-98
 -, third-order susceptibility 92
 Digicon 188
 Dipole approximation 105, 211
 - forbidden transitions 144
 - matrix elements 33
 Dipole-quadrupole scattering 169, 170
 Dipole radiation 22
 Disorder, electrical 78, 87
 -, mechanical 78
 Double resonance interference, 4WM 232-236, 233
 Dye lasers 44, 229
 Dynamic range 202
 - -, intrascenic 192, 203
 - -, ISIT 188
 - -, ISPD 189-192
 - -, memory 192, 203
 - -, SEC 182, 183
 - -, single shot 203

- -, SIT (EBS) 185, 187
- -, tracking 204
- EBS (electron bombardment silicon) 184, 202
- EDN (equivalent dark noise) 202
- Effective mass 103, 119
 - -, tensor 103
- EGG-PAR 187, 188, 192
- Eigenvectors, vibrational 30
- Einstein relations 87
- Elastic scattering, classical theory 22
 - -, cross section 22
 - -, solids 26
- Elasto-optic constants 28, 67, 150, 163–167
 - -, E_0 , $E_0 + \Delta_0$ contribution 150, 151
 - -, E_1 , $E_1 + \Delta_1$ contribution 151
- Elasto-optic mechanism, Brillouin scattering 74–76
 - - tensor 74
- Electron gains, in channel plates 181
- Electron-phonon interaction 33, 42, 218
 - -, first-order 36, 37
 - -, for excitons 137, 138
 - -, second-order 37, 138
 - -, symmetry restrictions 34
- Electron read beam
 - - -, of ISIT 183
 - - -, of SEC 183
 - - -, for selective scanning 177
 - - -, of SIT 184, 185
- Electron two-phonon deformation potential D 161
 - - - - D_1 , D_{15} , D_{25} , $D_{3,0}^3$ 62
- Electronic gating
 - - of image intensifier 181, 182
 - - of ISIT 188
 - - of ISPD 181, 182
 - - of SEC 183, 187
 - - of SIT (EBS) 187
 - - repetition rate 201
- Electronic scattering 2, 4, 102–104
- Electro-optic effect 60, 61
- Electrostatic intensifiers, single-stage 181, 182
- Energy bands, parabolic 112–116
- ERMA photocathode 180, 181, 187, 202
- Exciton interaction 116, 117, 135–138
- Exciton, LO-phonon bound states 150
- Excitons 135–138, 144
- Factor group analysis 50–55
- Faust-Henry coefficient 58–62
- FeBO₃ 15
- Fe₂O₃ 13
- Fermi's golden rule 219
- Fiber optics 182, 183
- First-order Raman scattering, resonant 33
- Fluctuations 28
 - dissipation theorem 56, 57
 - electric field 57, 58
 - entropy 28
 - polarizability 41, 42, 84
 - polarization 89
- Fluorites 64
- Forbidden LO scattering, $2d$ critical points 133, 134
 - - -, $3d$ critical points 132, 133
 - - -, electric field induced 134, 135
 - - -, heuristic approach 130–132
- Four-wave mixing (4WM) 208, 211, 212, 216, 222, 229
 - -, degenerate (D4WM) 230, 231
- Frame 202
- Frank-Condon formulation 105–109, 145, 147–150, 167
- Frequency doubling 210
- Fröhlich interaction 128, 145
 - -, constant C_F 129
 - -, excitons 137, 138
 - -, interband 129, 170
 - -, intraband 61, 128, 129
- f -sum rule 106
- Fundamental absorption edge 42
- GaAs 53, 62, 60, 103, 104, 117, 143, 152, 153, 160, 165
 - -, pressure coefficient of refractive index 166
 - -, resonant second-order scattering 159–161
 - -, resonant spin-flip scattering 104
 - -, scattering efficiency 93
- Gain, light 203
 - -, MCP 189
 - -, Raman 89, 209, 219
- GaP 62, 117, 136, 143, 165, 167
 - -, piezo-optic constants
 - -, resonant first-order scattering 152, 153
 - -, scattering efficiency 93
- GaS 152
- GaSb 62, 165
- GaSe, resonant scattering by phonons 109, 152
- GeSe₂ glasses 82
- GeO₂, amorphous Raman spectra 83
- Germanium 64, 117, 123, 167
 - -, amorphous 76, 77
 - -, band structure 118
 - -, bond polarizability 66, 67
 - -, elasto-optic constants 67
 - -, Raman polarizability a 68, 93
 - -, scattering efficiency 93
 - -, second-order resonant scattering 160
 - -, second-order spectrum 65
- Graphite intercalation compounds 4

- Hanle effect 147
 Heavy hole bands 122
 Holographic gratings 193
 HRS (hyper-Raman spectroscopy) 207–211,
 213, 215, 216, 218, 221, 222, 236–241
 –, experimental 237, 238
 –, resonant 241
 –, selection rules 236, 237
 –, spontaneous by phonons 238
 –, spontaneous by polaritons 238
 –, stimulated 241
 H_2 , scattering cross section 98
 Hybridization, p - d in Cu_2O 169
 Hydrocarbons, Raman polarizability 68
 Hyper-Brillouin scattering 239
 Hyper-polarizability 210
 Hyper-Rayleigh line 239
- I_2 34, 35
 $InAs$ 62, 74, 152, 165, 167
 –, imaginary part of susceptibility 118
 InP 62, 117, 152, 165
 –, scattering efficiency 93
 $InSb$ 62, 74, 117, 154, 165, 229, 231, 232
 –, resonance scattering 156, 159
 Image intensifiers and detectors 180–192
 – isocon 180
 – orthicon 180
 Infrared absorption, field-induced 97
 Instrumentation, recent advances 6
 Interaction hamiltonian 99–102
 Internal strain parameter ζ 67, 124
 ISIT (intensified silicon intensified target)
 180, 182, 184, 187, 188, 199, 201, 203
 ISPD (intensified silicon photodiode arrays)
 180, 181, 188–192, 201
 –, definition 203
 – diode structure diagram 189
 – noise sources 191
 – schematic diagram 190
- Jobin Yvon 193
- KBr , second-order scattering efficiency 94
 KCl 183
 KI , second-order scattering efficiency 94
 Kerr effect 220
 $k \cdot p$ relation 103, 119
 Kramers-Kronig transform 221
- Lag 201, 203
 –, definition 203
 –, ISIT (same as SIT)
 –, ISPD 190–192
 –, SEC 183
 –, SIT 185, 186
 –, SPD 190
- Landau-Placzek relation 28
 Laser annealing 10
 –, frequency doubled 6
 –, nitrogen 226
 –, Q -switched Nd-YA6 226, 238
 Lasers, CO 231
 –, CO_2 229
 –, cw vs. pulsed 219
 –, dye 44, 229
 –, free electron 6
 –, Q -switched ruby 238
 Layer materials, recent advances 11
 Lifetimes, intermediate state 167
 Light gain, MCP 181
 – hole bands 122
 $LiNbO_3$, CARS 230
 –, HRS 238
 Line shape 31, 36, 40, 218, 223, 232
 Linear photodiode arrays 179
 – – –, ISPD 180, 188–192, 199
 – – –, silicon diodes 188–192
 – – –, SPD 188–192
 Local fields 61
 LO phonon-plasmon coupled modes 2
 – scattering, forbidden 128–135
 lp/mm 203
 Lyddane-Sachs-Teller relation 129
- Mg_2Ge 152
 –, scattering efficiency 93
 Mg_2Si 152
 –, scattering efficiency 93
 Mg_2Sn 152
 –, scattering efficiency 94
 Magnetic excitations 4, 5, 32
 – semiconductors 5
 Magnons 4, 42
 Matrix element, dipole 117
 MCP (microchannel plates) 180, 181, 188, 203
 Metallization 68
 Metalloporphyrins 109
 Metals 4
 –, “synthetic” 4
 Microprobe, Raman 198
 Microscopic theory, first-order Raman effect
 4, 110
 Modulation spectroscopy 28
 Morphic effects 5
 Multichannel analyser 179
 – detection 179–204
 Multiphonon scattering 145–150, 167, 168
 Multistage spectrographs 192–194
- N_2 , absolute cross section 37, 98
 –, rotational spectrum 29
 $NaCl$ 228

- NaNO₃, cross section 92, 94
 –, HRS 238
 NbSe₂ 11
 Nb₃Sn 86
 NH₄Br 238
 NH₄Cl 238
 Nitrobenzene, cross section 93
 Noise, fixed pattern 202
 –, ISPD 191
 Nonadiabatic terms 109
 Nonresonant contribution to $X^{(3)}$ 214
 Normal mode coordinate, molecules 30
 Nyquist criterion 202
- OHD RIKES (optical heterodyne RIKES)**
 211
OMA (optical multichannel analyzer) 179,
 180, 194, 196, 199
 –, applications 197–201
 –, pulsed spectroscopy 200, 201
 –, spatial resolution 198
 One-dimensional solids, organic 116
 Optical properties of semiconductors 117
- PARS (Photoacoustic Raman spectroscopy)**
 211
 Penn model 116, 120
 Permittivity 22
 Phase matching 226
 – mismatch 213, 219
 Phonon, amplitude 31
 – eigenvectors, diamond, CaF₂, ZnS 53
 –, piezoelectric 74, 128
 Phosphor, P-11, P-20 181
 –, persistence 191
 Photocathode
 – of electrostatic intensifiers 181
 – of ISPD array 188
 – of MCP intensifier 180
 – of SEC camera 182
 – of SIT camera 183
 –, S-20, S-21 180, 181
 Photoelastic tensor (*see also* elasto-optic tensor)
 73
 Photographic plates 179
 Photomultiplier 179
 Photon counting 179
 Piezobirefringence 74, 164
 Piezo-optic constants 164, 165
 Pixels 194
 Plasmons 42
 –, acoustic 70
 Polaritons 5, 58–60, 213, 240, 241
 Polarizability, anharmonic
 –, imaginary part
 –, Raman 32, 52, 122
 – tensor 22, 23, 208
 – theory 20, 106
 Polarization active spectroscopy 220
 Preamplifier noise, OMA 185, 191
 Pressure effects 5
 Pseudopotential, form factors 124
 Pseudopotential theory, E_0 absorption edge
 117
- Quadrupole transitions 169
 Quality factor 24
 Quantum-noise-limited detection, with ISIT
 187
 –, with ISPD 188
 –, with SEC 183
 –, with SIT 185
 Quantum-noise-limited detector 179, 180
 – theory 99–155
 Quasistatic approximation 20
- Radiative recombination time 145
 Radius of electron r_e 24
 Raman cross sections, absolute 37
 – microprobe 198
 – polarizability, α 52, 53, 68, 122
 – – –, sign α 98
 – –, Frank-Condon 107
 – –, Herzberg-Teller 108
 Raman detection, CARS 201
 –, cw 197
 –, boxcar aperturing 201
 –, microprobe 198
 –, pulsed 200, 201
 –, Ramanography 199
 –, temporal evolution 199
 Raman scattering, by LO phonons 58–62
 –, by plasmons 103
 –, defect-induced 85
 –, electronic 102–104
 – – in crystals, first-order 38
 – – –, second-order 62
 –, second-order resonant 35
 –, spontaneous 209
 –, stimulated 87–89, 96, 207
 – susceptibilities 2
 –, E_1 , $E_1 + \Delta_1$ contribution 124–126
 –, E_0 , $E_0 + \Delta_0$ edge contribution 121–124
 –, E_2 contribution 126
 –, E'_0 contribution 126
 –, Feynman diagrams 110
 –, fluorite-type materials 127, 128
 –, one-phonon 120, 136
 –, second-order 62, 63, 141, 158
 –, third-order 20
 Raman tensor, antisymmetric 42, 104
 – –, forth rank $I_{\alpha\beta\gamma\delta}$ 41
 – –, R_{ij} 45–49
 – –, R_{klm} 50

- -, sign 53
- Ramanography 199
- Rare earth chalcogenides 5, 86
- RbI 238
- RCA 203
- Reciprocal lattice vector 26
- Resolution, OMA 203
- Resonance, in-going 109
- , one-photon 215
- , outgoing 109
- , Raman 217
- scattering, wurtzite 154, 155
- , two-photons 215
- Resonant forbidden LO scattering 158
- - LO scattering, GaAs 154
- - LO scattering, InSb 156
- Resonant scattering 2, 209
- -, a-Si 79
- -, under stress 156, 157
- - by phonons, E_0 , $E_0 + \Delta_0$ gap 152-155
- - by phonons, E_1 , $E_1 + \Delta_1$ gaps 155-158
- - by phonons, exciton interaction 135-138
- - by phonons, experiments 151-172
- - by phonons, polaron effects 137
- Resonant second-order scattering E_1 , $E_1 + \Delta_1$ gaps 162, 163
- Response correction 197
- Reticon 188, 191
- RIKES (Raman-induced Kerr effect spectroscopy) 207, 211, 215, 216, 218, 220, 221, 231, 232
- Ripple mechanism, Brillouin scattering 74-76
- Rotational bands 37

- SiF₄ 76
- SiH₄ 76
- SiO₂ (quartz), cross section 92, 94
- SiO₂, glasses 82
- (SN)_x 15
- SrF₂, scattering efficiency 94, 98, 127, 128
- SrTiO₃, HRS 238-241
- , second-order scattering efficiency 94
- , silent modes 237
- Scanning spectrometers 192
- Scattering, anti Stokes 31, 36
- by molecules, inelastic 29
- by phonons, phenomenological theory 2
- , Bragg 27
- , combination 31, 36
- , depolarized 24, 104
- , difference 31, 36
- , disorder-induced 20
- , E -dependent 19
- efficiencies, absolute 93, 94, 111, 225
- efficiency, and Raman gain 89, 219
- -, as a function of Raman polarizability 95, 153
- -, Brillouin-Raman method 96
- -, CARS 90, 228
- -, hyper-Raman 222, 236
- - sample substitution 95
- efficiency, LO/TO ratio method 97, 98
- efficiencies: relative units 19, 40
- -, second order 19
- , forbidden
- length
- , overtone 30, 36
- , polarized 23
- , q -dependent 19
- , quasielastic 84, 85
- , Rayleigh 30
- , resonant 24
- , rotational 29
- , rotational-vibrational 29
- , Stokes 31, 36
- , Thompson 22
- , vibrational 29
- volume V 40
- Schott glass 84
- SEC (secondary electron conduction) cameras 180, 182, 183, 199, 201, 203
- Second-order deformation potential and temperature dependence of gaps 142
- - -, pseudopotential theory 140
- - -, renormalized \bar{D}_1 141
- - scattering E_0 , $E_0 + \Delta_0$ contribution 141
- - scattering E_1 , $E_1 + \Delta_1$ contribution 141
- - -, cascade processes 138
- - -, experiments 158-163
- - -, $H_{\text{cV}}^{(1)}$ effects 144
- - -, perturbation theory 139
- Selection rules 45
- - for scattering by diamond-zincblende phonons 49
- -, parity 50
- -, second-order scattering 63
- Selenium, scattering efficiency 93
- Semiconductors, recent advances 8
- Sensitivity, OMA 203
- Silent modes 207, 210, 222, 237, 241
- Silicon 64, 117, 123, 152, 167
- , amorphous 76-81
- , bond polarizability 66, 67
- , boron-doped 85
- , cross section 93
- , elastooptic constants 67
- , lattice dynamics 65
- , polycrystalline 80
- , Raman polarizability α 68

- , resonant first-order scattering 158
- , resonant second-order scattering 143, 160
- , second-order Raman spectra 63, 143, 158
- Silver halides 143, 172
- SIT (silicon intensified target) 180, 183–188, 199, 201, 203
 - camera 183–187
 - camera, definition 203
 - for temporal evolution 199
- , lag of 185, 186
- performance limitations 185
- schematic diagram 182
- signal-to-noise 197
- Sodium 241
- Solid-state detectors, linear array 179
- Spatial filter 209, 226
- Spatial resolution, electrostatic intensifiers 182
 - , multichannel detectors 181
- SPD (self-scanned linear photodiode array) 204
- Spectrograph, bandpass 183, 184
 - , multistage 179
 - , schematic diagram 193
 - , stray light rejection 192, 194, 202
 - , subtractive dispersion 193
 - , triple stage 192, 193
- Spex triplemate spectrometer 193, 194
- Spin-dependent effects 13
- Spin-flip scattering, resonant 104, 152
- Spin-orbit splitting,
 - Δ_0 117
 - Δ_1 119, 125
 - , negative 169
- Splitting, LO-TO 59, 82
- SRS (stimulated Raman spectroscopy) 207, 215, 216
- Stokes-antistokes ratio 32
- Stray light rejection 179, 192
- Superconductors 12
- Superionic conductors 4
- Superlattices, recent advances 10
- Surface enhanced Raman scattering (SERS) 5, 14, 200
- Surfaces, recent advances 9
- Susceptibility, effect of inversion symmetry 213
 - , higher order 207
 - , non-linear 211–215
 - , odd rank 213
 - , one-dimensional critical points 116
 - , Raman 39
 - tensor, $\chi^{(3)}$, $\chi^{(5)}$ 214
 - , third-order 2, 87
 - , three-dimensional critical points 113
 - , two-dimensional critical points 116
 - , χ' 39
- Symmetry properties 42
- Synchrotron radiation 6
- TaS₃ 11
- TiC, Raman Spectra 86
- TiN 12
- TiO₂ 238, 241
- TTF-TCNQ 15
- Television cameras 179, 180, 182, 187, 188, 199, 201
- Temporal dependence of scattering 2, 199
- Thermionic emission rate 183
- Thermo-optic constant 28
- Three-band terms 34, 123, 153
- TPA (two-photon absorption) 215, 232, 234
 - , experimental setup 234
- Tracor Northern 188, 192
- Transition polarizability 106
 - , hyper-Raman 222
 - susceptibility 106
- Two band terms 34, 122, 153
- Two-wave mixing 213
- Units, atomic 21, 100
 - , cgs 211, 217
 - , SI 21, 217
- V₃Si 12, 86
- Veiling glare 192, 204
- Vidicon 180, 204
- Vignetting 197
- Vitreous silica, Brillouin scattering 85
 - , Raman scattering 84, 85
 - , ultrasonic attenuation 84
- Whestinghouse 183, 186
- Wurtzite 53, 54, 58
- Xerography 76
- YS 12
- ZnO 167
- ZnO, scattering efficiency 93
- ZnS 43, 58, 62, 68, 152, 160, 165
 - , scattering efficiency 93, 152
- ZnSe 62, 68, 74, 152, 160, 165, 167
 - , resonant Brillouin scattering 75
 - , scattering efficiency 93
- ZnTe 42, 43, 62, 68, 152, 153, 158, 160, 165, 167
 - , scattering efficiency 93
 - , second-order Raman spectrum 69
- Zincblende 53, 54, 58